Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.185 inches
Terminal Length:
1.500 inches
Overall Diameter:
0.370 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
То-5
Electrode Internally-electrically Connected To Case:
Collector
Component Name And Quantity:
2 transistor
Mounting Method:
Terminal
Terminal Circle Diameter:
0.200 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon all transistor
Voltage Rating In Volts Per Characteristic:
40.0 collector to emitter voltage, dc all transistor and 40.0 collector to base voltage, dc all transistor
Current Rating Per Characteristic:
20.00 milliamperes source cutoff current all transistor
Power Rating Per Characteristic:
500.0 milliwatts small-signal input power, common-collector preset all transistor
Maximum Operating Tempurature Per Measurement Point:
85.0 degrees celsius junction
Special Features:
All transistor junction pattern arrangement: npn
Terminal Type And Quantity:
6 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0